TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74AC112P,TC74AC112F

Dual J-K Flip Flop with Preset and Clear

The TC74AC112 is an advanced high speed CMOS DUAL J-K FLIP FLOP fabricated with silicon gate and double-layer metal wiring C^2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

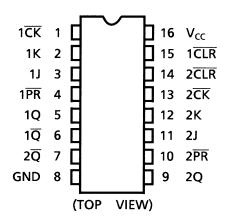
In accordance with the logic level given J and K input this device changes state on negative going transition of the clock pulse. \overline{CLEAR} and \overline{PRESET} are independent of the clock and accomplished by a low logic level on the corresponding input.

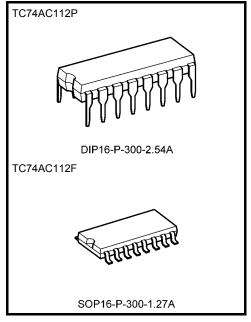
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- High speed: $f_{max} = 170 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A$ (max) at $T_a = 25$ °C
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
- Symmetrical output impedance: $|I_{OH}| = I_{OL} = 24$ mA (min) Capability of driving 50 Ω transmission lines.
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V_{CC} (opr) = 2 to 5.5 V
- Pin and function compatible with 74F112

Pin Assignment

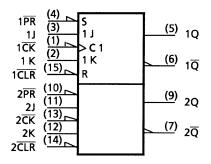




Weight

DIP16-P-300-2.54A : 1.00 g (typ.) SOP16-P-300-1.27A : 0.18 g (typ.)

IEC Logic Symbol

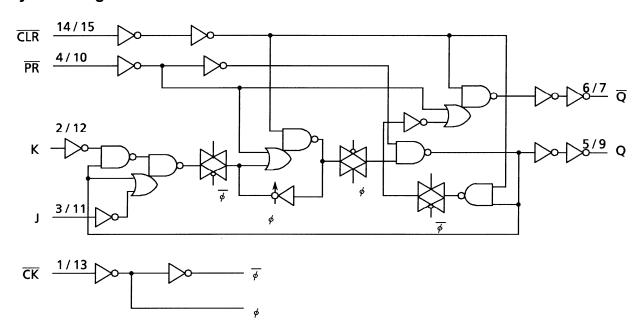


Truth Table

	Inputs						Function	
CLR	PR	J	K	CK	Q	ΙQ	Function	
L	Н	Х	Х	Х	L	Н	Clear	
Н	L	Х	Х	Х	Н	L	Preset	
L	L	Х	Х	Х	Н	Н		
Н	Н	L	L	\rightarrow	Qn	\overline{Q}_n	No Change	
Н	Η	Ш	Η	\rightarrow	L	Η		
Н	Н	Н	L	\neg	Н	L		
Н	Н	Н	Н	\Box	\overline{Q}_n	Qn	Toggle	
Н	Н	Х	Х		Qn	\overline{Q}_n	No Change	

X: Don't care

System Diagram



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Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	−0.5 to 7.0	٧
DC input voltage	V _{IN}	-0.5 to V _{CC} + 0.5	V
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
Input diode current	I _{IK}	±20	mA
Output diode current	lok	±50	mA
DC output current	lout	±50	mA
DC V _{CC} /ground current	Icc	±100	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T _{stg}	−65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C should be applied up to 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit	
Supply voltage	V _{CC}	2.0 to 5.5	V	
Input voltage	V _{IN}	0 to V _{CC}	V	
Output voltage	V _{OUT}	0 to V _{CC}	V	
Operating temperature	T _{opr}	−40 to 85	°C	
Input rise and fall time	dt/dV	0 to 100 ($V_{CC} = 3.3 \pm 0.3 \text{ V}$)	ns/V	
input rise and fail tille	ui/uv	0 to 20 (V _{CC} = 5 \pm 0.5 V)		

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition V _{CC} (V)			Ta = 25°C			Ta = -40 to 85°C		- Unit		
Ondracteristics	Cymbol					Min	Тур.	Max	Min	Max	OTHE	
				2.0	1.50	_	_	1.50	_			
High-level input voltage	V_{IH}			3.0	2.10	_	_	2.10	_	V		
				5.5	3.85	_	_	3.85	_			
					2.0	_	_	0.50	_	0.50		
Low-level input voltage	V_{IL}		_		3.0	_	_	0.90	_	0.90	V	
C					5.5	_	_	1.65	—	1.65		
			I _{OH} = -50 μA		2.0	1.9	2.0		1.9	_	V	
	V _{ОН}	V _{IN} = V _{IH} or V _{IL}			3.0	2.9	3.0	_	2.9	_		
High-level output					4.5	4.4	4.5	_	4.4	_		
voltage			$I_{OH} = -4 \text{ mA}$		3.0	2.58	_		2.48	_	V	
			$I_{OH} = -24 \text{ mA}$		4.5	3.94	_	_	3.80	_		
			$I_{OH} = -75 \text{ mA}$	(Note)	5.5	_	_	_	3.85	_		
	V _{OL}	VIN = VIH or VIL			2.0	_	0.0	0.1	_	0.1		
			$I_{OL} = 50 \mu A$		3.0	_	0.0	0.1	_	0.1		
Low-level output					4.5	_	0.0	0.1	_	0.1	V	
voltage			I _{OL} = 12 mA		3.0	_	_	0.36	_	0.44	V	
			$I_{OL} = 24 \text{ mA}$		4.5	_	_	0.36	_	0.44		
			$I_{OL} = 75 \text{ mA}$	(Note)	5.5		_	_	_	1.65		
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		5.5	_	_	±0.1	_	±1.0	μА		
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	_	_	4.0	_	40.0	μА		

Note: This spec indicates the capability of driving 50 Ω transmission lines.

One output should be tested at a time for a 10 ms maximum duration.



Timing Requirements (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C	Ta = -40 to 85°C	Unit
			V _{CC} (V)	Limit	Limit	
Minimum pulse width	t _{W (L)}		3.3 ± 0.3	7.5	7.5	ns
(\overline{CK})	t _{W (H)}	_	5.0 ± 0.5	5.0	5.0	115
Minimum pulse width	4		3.3 ± 0.3	7.0	7.0	20
($\overline{CLR},\;\;\overline{PR})$	t _{W (L)}	_	5.0 ± 0.5	5.0	5.0	ns
Minimum set-up time	4		3.3 ± 0.3	11.0	11.0	20
Willimum Set-up time	t _S	_	5.0 ± 0.5	6.0	6.0	ns
Minimum hold time	4.		3.3 ± 0.3	0.0	0.0	20
Minimum noid time	t _h	_	5.0 ± 0.5	0.0	0.0	ns
Minimum removal time	4		3.3 ± 0.3	3.0	3.0	20
(CLR , PR)	t _{rem}	_	5.0 ± 0.5	2.0	2.0	ns

AC Characteristics (C_L = 50 pF, R_L = 500 Ω , input: t_r = t_f = 3 ns)

Characteristics	Symbol	Test Condition	Ta = 25°C			Ta = -40 to 85°C		Unit	
	- ,		V _{CC} (V)	Min	Тур.	Max	Min	Max	
Propagation delay time ($\overline{\text{CK}}$ -Q, $\overline{\text{Q}}$)	t _{pLH} t _{pHL}	_	3.3 ± 0.3 5.0 ± 0.5		9.1 6.5	15.5 9.4	1.0 1.0	17.8 10.8	ns
Propagation delay time (CLR, PR-Q, Q)	t _{pLH}	_	3.3 ± 0.3 5.0 ± 0.5	_	8.6 5.8	14.6 8.3	1.0 1.0	16.8 9.6	ns
Maximum clock frequency	f _{max}	_	3.3 ± 0.3 5.0 ± 0.5	45 80	90 150	_ _	45 80	_	MHz
Input capacitance	C _{IN}	_		_	5	10	_	10	pF
Power dissipation capacitance	C _{PD} (Note)			_	85	_	_	_	pF

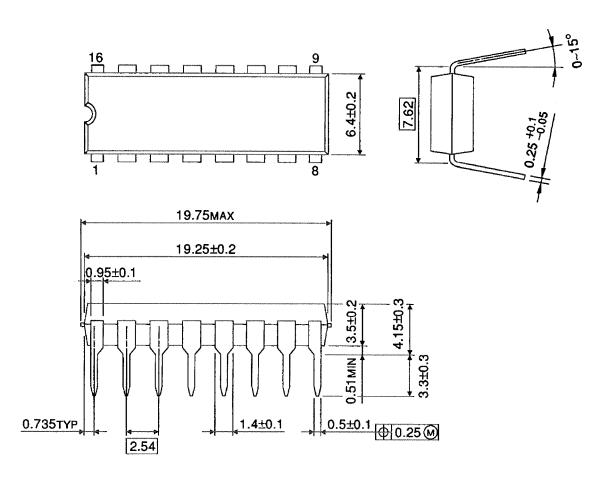
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC}$$
 (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$ (per F/F)

Package Dimensions

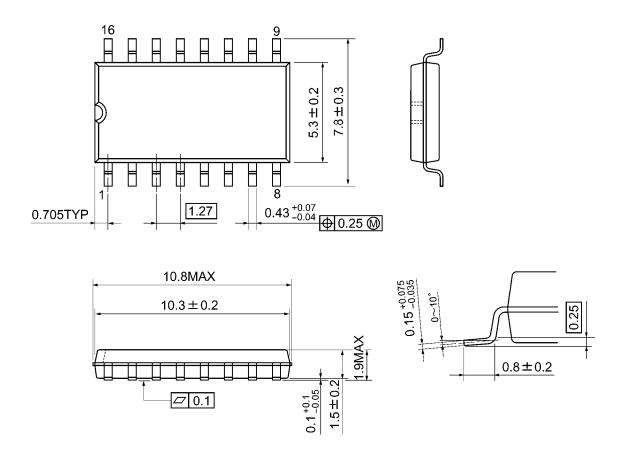
DIP16-P-300-2.54A Unit: mm



Weight: 1.00 g (typ.)

Package Dimensions

SOP16-P-300-1.27A Unit: mm



Weight: 0.18 g (typ.)

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